NSN 5961-01-049-8545

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View Online at https://aerobasegroup.com/nsn/5961-01-049-8545 **Inclosure Material:** Metal **Overall Length:** Between 0.460 inches and 0.505 inches **Overall Height:** Between 0.140 inches and 0.190 inches **Overall Width:** Between 0.380 inches and 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 65.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 27914-12074 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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